

Description

The ASMF05 is a 5V TVS array, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The ASMF05 complies with the IEC 61000-4-2 (ESD) with ±30kV air and ±30kV contact discharge. It is assembled into a 5-Pin lead-free SOT-353 package. The low clamping voltage array make it ideal for use in portable electronics such as cell phones, PDAs, and digital cameras.

Features

- Low leakage current
- Operating voltage: 5V
- Low clamping voltage
- JEDEC SOT-353 package
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV Contact discharge: ±30kV

- IEC61000-4-5 (Lightning) 22A (8/20µs)

RoHS Compliant

Mechanical Characteristics

Package: SOT-353Lead Finish: Matte Tin

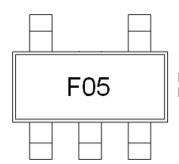
Case Material: "Green" Molding Compound.Terminal Connections: See Diagram Below

Marking Information: See Below

Applications

- Peripherals
- Industrial Equipment
- Notebook Computers
- Portable Instrumentation
- Microprocessor Based Equipment
- Cell Phone Handsets and Accessories
- Personal Digital Assistants (PDAs) and Pagers

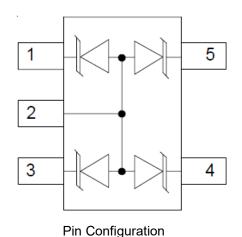
Marking Information



F05 = Device Marking Code Dot denotes Pin1

Ordering Information

Dimensions and Pin Configuration



Part Number	Packaging	Reel Size	
ASMF05	3000/Tape & Reel	7 inch	



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	300	W
Peak Pulse Current (8/20µs)	IPP	22	Α
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	VESD	±30 ±30	kV
Operating Temperature Range	TJ	−55 to +125	°C
Storage Temperature Range	Tstg	−55 to +150	°C

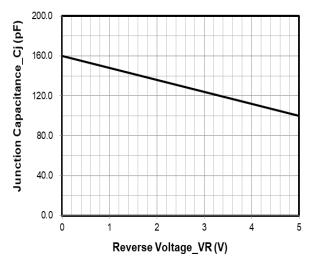
Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Reverse Breakdown Voltage	VBR	6			V	IT = 1mA
Reverse Leakage Current	I _R			0.5	μA	VRWM = 5V, any I/O pin to ground
Clamping Voltage	Vc			7	V	IPP = 1A (8 x 20μs pulse), any I/O pin to ground
Clamping Voltage	Vc			14	V	IPP = 22A (8 x 20µs pulse), any I/ O pin to ground
Junction Capacitance	СЛ		160		pF	VR = 0V, f = 1MHz, any I/O pin to ground

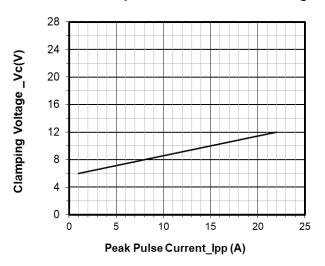
Note 1: I/O pins are Pin 1, 3, 4, 5



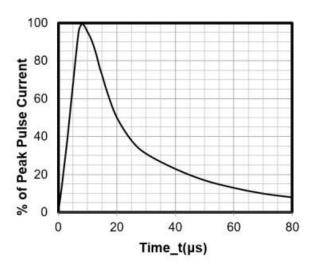
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



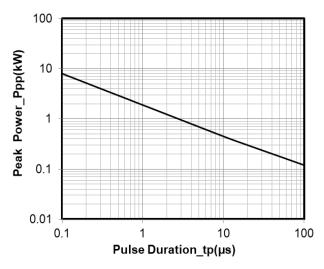
Junction Capacitance vs. Reverse Voltage



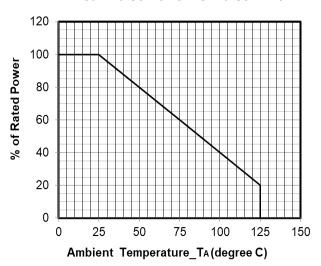
Clamping Voltage vs. Peak Pulse Current



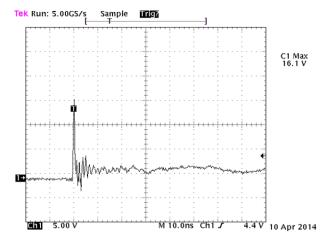
8 X 20µs Pulse Waveform



Peak Pulse Power vs. Pulse Time



Power Derating Curve



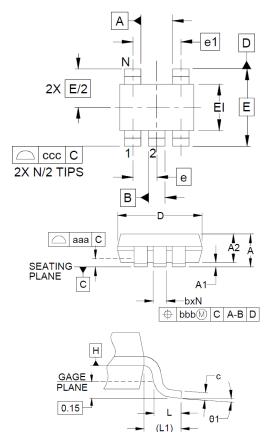
Note: Data is taken with a 10x attenuator

ESD Clamping Voltage

8 kV Contact per IEC61000-4-2



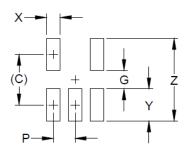
SOT-353 Package Outline Drawing



	DIMENSIONS					
DIM	INCHES			MILLIMETERS		
ואווט	MIN	NOM	MAX	MIN	NOM	MAX
Α	-	-	.043	-	-	1.10
A1	.000	-	.004	0.00	-	0.10
A2	.028	.035	.039	0.70	0.90	1.00
b	.006	-	.012	0.15	-	0.30
С	.003	-	.009	0.08	-	0.22
D	.075	.079	.083	1.90	2.00	2.10
E1	.045	.049	.053	1.15	1.25	1.35
Е	.083 BSC			2.10 BSC		
е	.026 BSC			0.65 BSC		
e1	.051			1.30 BSC		
L	.010	.014	.018	0.26	0.36	0.46
L1	(.017)			(0.42)		
Ν	5			5		
0 1	0°	-	8°	0°	-	8°
aaa	.004			0.10		
bbb	.004			0.10		
CCC	.012			0.30		

Sug-

gested Land Pattern



SYM	DIMENSIONS			
	MILLIMETERS	INCHES		
С	1.85	0.073		
G	1.00	0.039		
Р	0.65	0.026		
Х	0.40	0.016		
Υ	0.85	0.033		
Z	2.70	0.106		

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